MPSA14 is a Preferred Device

# **Darlington Transistors**

### **NPN Silicon**

#### **Features**

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CES</sub>	30	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	30	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	10	Vdc
Collector Current – Continuous	Ic	500	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

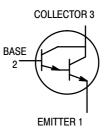
Characteristic	Symbol	Max	Unit		
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/mW		
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/mW		

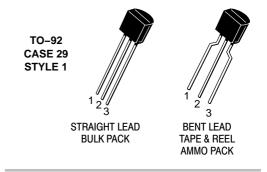
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



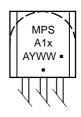
#### ON Semiconductor®

http://onsemi.com





#### **MARKING DIAGRAM**



x = 3 or 4

A = Assembly Location

Y = Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Characteristic						
OFF CHARACTERISTICS	•				ı		
Collector – Emitter Breakdown Voltage ( $I_C = 100 \mu Adc, I_B = 0$ )		V <sub>(BR)CES</sub>	30	-	Vdc		
Collector Cutoff Current (V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)		I <sub>CBO</sub>	-	100	nAdc		
Emitter Cutoff Current (V <sub>EB</sub> = 10 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	-	100	nAdc		
ON CHARACTERISTICS (Note 1)			•		•		
DC Current Gain ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ ) ( $I_C = 100 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	MPSA13 MPSA14 MPSA13 MPSA14	h <sub>FE</sub>	5,000 10,000 10,000 20,000	- - -	-		
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 0.1 mAdc)		V <sub>CE(sat)</sub>	-	1.5	Vdc		
Base – Emitter On Voltage (I <sub>C</sub> = 100 mAdc, V <sub>CE</sub> = 5.0 Vdc)		V <sub>BE(on)</sub>	-	2.0	Vdc		
SMALL-SIGNAL CHARACTERISTICS			•		•		
Current–Gain – Bandwidth Product (Note 2) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 5.0 Vdc, f = 100 MHz)		f <sub>T</sub>	125	_	MHz		

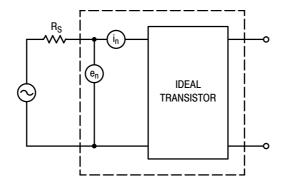
<sup>1.</sup> Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MPSA13	TO-92	5000 Units / Bulk
MPSA13G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSA13RLRA	TO-92	2000 / Tape & Reel
MPSA13RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA13RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA13RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA13ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA14G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSA14RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA14RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>2.</sup>  $f_T = |h_{fe}| \cdot f_{test}$ .



**Figure 1. Transistor Noise Model** 

#### **NOISE CHARACTERISTICS**

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$ 

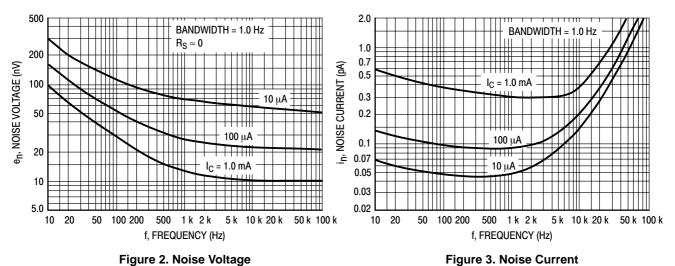


Figure 2. Noise Voltage

BANDWIDTH = 10 Hz TO 15.7 kHz

100 μΑ

1.0 mA

200

100

70

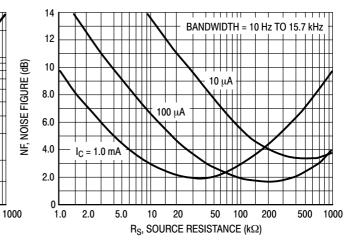
50

30

20

10 1.0 2.0

V<sub>T</sub>, TOTAL WIDEBAND NOISE VOLTAGE (nV)



 $R_S$ , SOURCE RESISTANCE ( $k\Omega$ ) Figure 4. Total Wideband Noise Voltage

50

100

Figure 5. Wideband Noise Figure

#### SMALL-SIGNAL CHARACTERISTICS

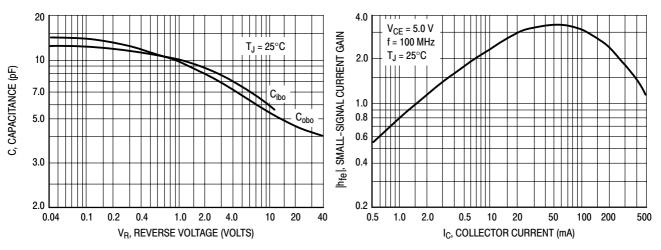


Figure 6. Capacitance

Figure 7. High Frequency Current Gain

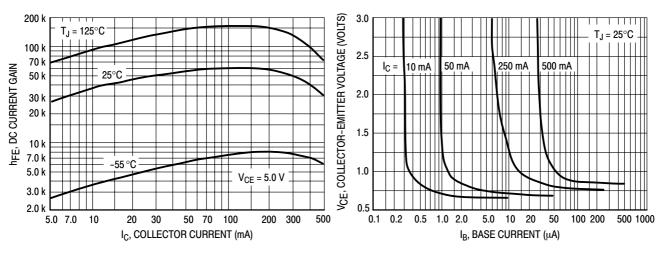


Figure 8. DC Current Gain

Figure 9. Collector Saturation Region

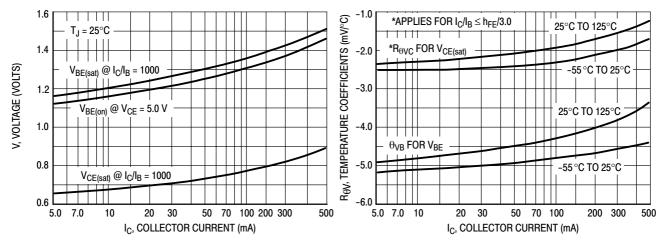


Figure 10. "On" Voltages

**Figure 11. Temperature Coefficients** 

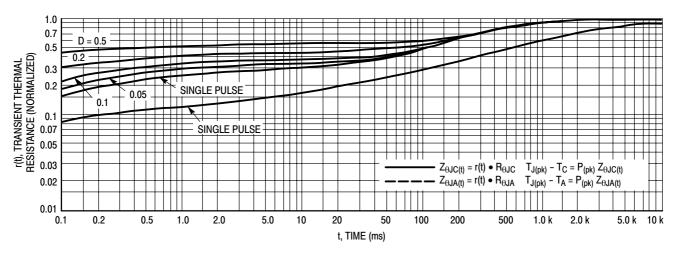


Figure 12. Thermal Response

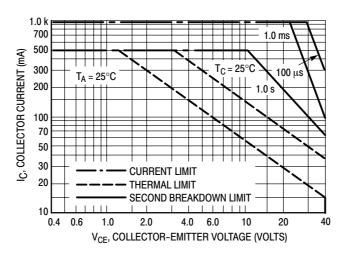
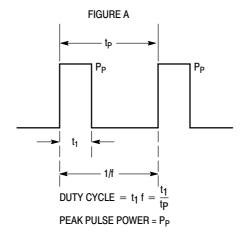
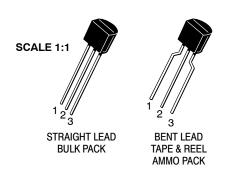


Figure 13. Active Region Safe Operating Area



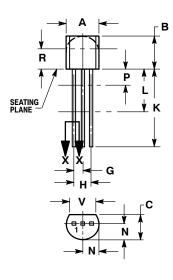
**Design Note: Use of Transient Thermal Resistance Data** 





**TO-92 (TO-226)** CASE 29-11 **ISSUE AM** 

**DATE 09 MAR 2007** 

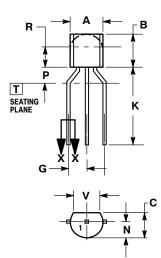


STRAIGHT LEAD **BULK PACK** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R
  IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS		
DIM	MIN	MAX	MIN	MAX		
Α	0.175	0.205	4.45	5.20		
В	0.170	0.210	4.32	5.33		
С	0.125	0.165	3.18	4.19		
D	0.016	0.021	0.407	0.533		
G	0.045	0.045 0.055		1.39		
Н	0.095	0.105	2.42	2.66		
J	0.015	0.020	0.39	0.50		
K	0.500		12.70			
L	0.250		6.35			
N	0.080	0.105	2.04	2.66		
Р		0.100		2.54		
R	0.115		2.93			
٧	0.135		3.43			



**BENT LEAD TAPE & REEL** AMMO PACK



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER

- AND BEYOND DIMENSION K MINIMUM.

	MILLIN	IETERS
DIM	MIN	MAX
Α	4.45	5.20
В	4.32	5.33
С	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	
N	2.04	2.66
P	1.50	4.00
R	2.93	
٧	3.43	

#### **STYLES ON PAGE 2**

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#### **TO-92 (TO-226)** CASE 29-11 ISSUE AM

#### **DATE 09 MAR 2007**

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	
PIN 1. 2.	GATE	PIN 1.	SOURCE	PIN 1.	DRAIN	PIN 1.	BASE 1	2.	CATHODE
2.	ANODE CATHODE & ANODE	2.	GATE	2.	ANODE 1 GATE CATHODE 2	2.	EMITTER COLLECTOR BASE	2.	ANODE 1 CATHODE ANODE 2
2.	ANODE GATE	PIN 1. 2.	COLLECTOR	PIN 1.	ANODE CATHODE NOT CONNECTED	PIN 1.	GATE	PIN 1. 2.	NOT CONNECTED CATHODE ANODE
PIN 1. 2.	COLLECTOR EMITTER	PIN 1.	SOURCE GATE	PIN 1. 2.		PIN 1. 2.	EMITTER COLLECTOR/ANODE CATHODE	PIN 1. 2.	MT 1
	Vcc	PIN 1.	MT SUBSTRATE		CATHODE ANODE	PIN 1. 2.	NOT CONNECTED ANODE CATHODE	PIN 1. 2.	DRAIN
PIN 1. 2.	GATE	PIN 1. 2.	BASE COLLECTOR EMITTER	PIN 1. 2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT		

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MPSA13 MPSA13G MPSA13RLRA MPSA13RLRAG MPSA13RLRAG MPSA13RLRAG MPSA13RLRAG MPSA13RLRAG MPSA14RLRAG MPSA